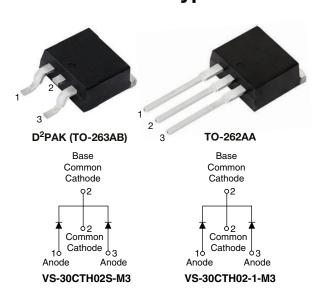


Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt®



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V_{R}	200 V				
V _F at I _F	0.78 V				
t _{rr} typ.	30 ns				
T _J max.	175 °C				
Package	D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

FEATURES

- · Hyperfast recovery time
- · Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Vishay Semiconductors 200 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage		V_{RRM}		200	V		
Average rectified forward current	per diode	I _{F(AV)}	T _C = 159 °C	15			
	per device			30	Α		
Non-repetitive peak surge current		I _{FSM}	T _C = 25 °C	200			
Operating junction and storage ten	nperatures	T_J , T_{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	200	-	-	V	
Campand walks as	V _F	I _F = 15 A	-	0.92	1.05	V	
Forward voltage		I _F = 15 A, T _J = 125 °C	-	0.78	0.85		
Payaraa laakaga aurrant	1	$V_R = V_R$ rated	-	-	10		
Reverse leakage current I _R		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	5	300	μΑ	
Junction capacitance	C _T	V _R = 200 V	-	57	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH	

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VS-30CTH02S-M3, VS-30CTH02-1-M3

DYNAMIC RECOVERY	CHARACTER	RISTICS (T _C = 2	5 °C unless otherv	vise speci	fied)		
PARAMETER	SYMBOL	TEST CO	ONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time		$I_F = 1 A$, $dI_F/dt = 8$	50 A/μs, V _R = 30 V	-	-	35	
		$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$		-	-	30	
	t _{rr}	T _J = 25 °C	I _F = 15 A dI _F /dt = 200 A/μs V _R = 160 V	-	26	-	ns A
		T _J = 125 °C		-	40	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2.8	-	
		T _J = 125 °C		-	6.0	-	
Reverse recovery charge	0	T _J = 25 °C	•	-	37	-	nC
	Q_{rr}	T _J = 125 °C		-	120	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}	-65	-	175	°C	
Thermal resistance, junction to case per diode	R _{thJC}	-	-	1.1	°C/W	
Weight		-	2.0	=	g	
weight		-	0.07	=	OZ.	
Mounting torque		6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Madding device		Case style D ² PA	AK (TO-263AB)	30CTH02S		
Marking device		Case style TO-262		30CTH02-1		

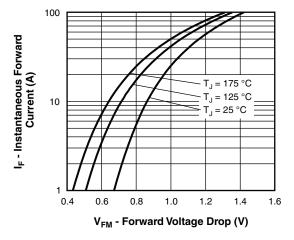


Fig. 1 - Maximum Forward Voltage Drop Characteristics

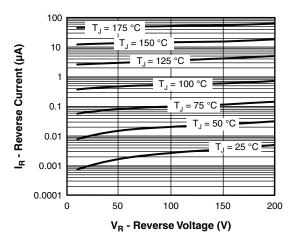


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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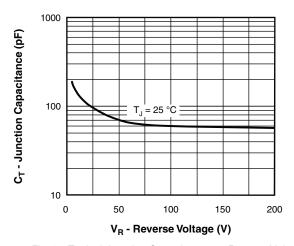


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

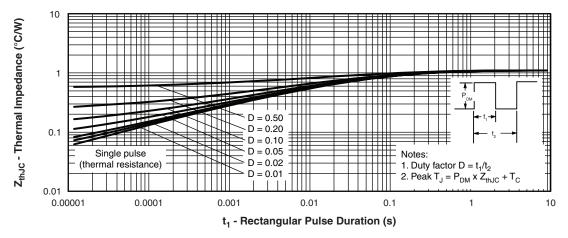


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

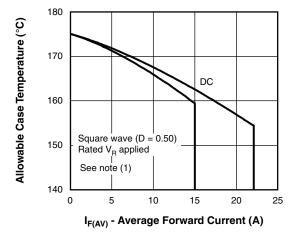


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

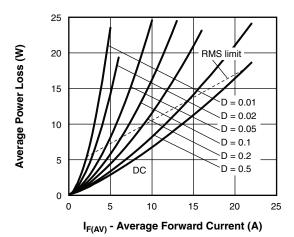


Fig. 6 - Forward Power Loss Characteristics

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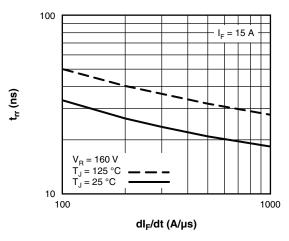


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

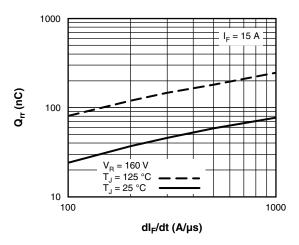
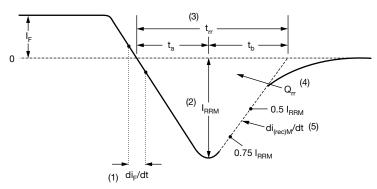


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{F}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

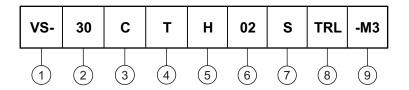
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-30CTH02S-M3, VS-30CTH02-1-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - C = common cathode

4 - T = TO-220, D²PAK (TO-263AB)

5 - H = hyperfast rectifier

6 - Voltage rating (02 = 200 V)

7 - • S = D^2PAK (TO-263AB)

• -1 = TO-262AA

None = tube (50 pieces)

• TRL = tape and reel (left oriented, for D²PAK (TO-263AB) package)

• TRR = tape and reel (right oriented, for D²PAK (TO-263AB) package)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-30CTH02S-M3	50	Antistatic plastic tubes				
VS-30CTH02STRL-M3	800	13" diameter plastic tape and reel				
VS-30CTH02STRR-M3	800	13" diameter plastic tape and reel				
VS-30CTH02-1-M3	50	Antistatic plastic tubes				

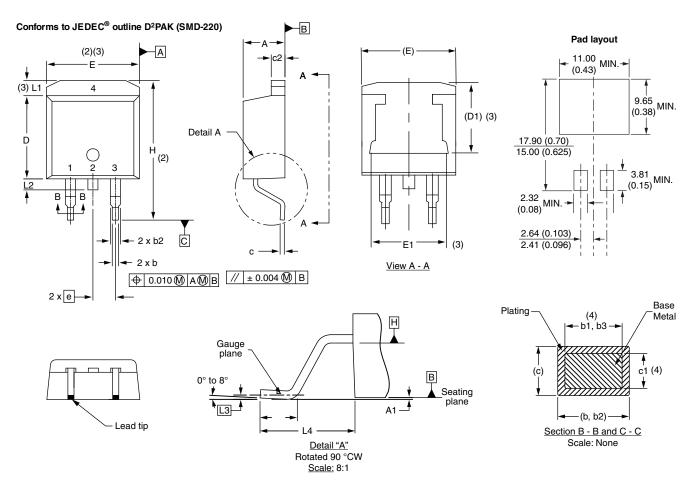
LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Doub and discussion for a section	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INCHES		TERS INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	0.00	0.254	0.000	0.010			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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